TOSHIBA Field Effect Transistor Silicon P Channel MOS Type

SSM3J15FS

High Speed Switching Applications Analog Switch Applications

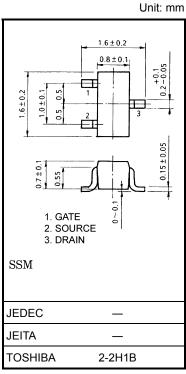
· Small package

• Low ON resistance : $R_{on} = 12 \Omega \text{ (max) (@V_{GS} = -4 V)}$

: $R_{on} = 32 \Omega \text{ (max) } (@V_{GS} = -2.5 \text{ V})$

Maximum Ratings (Ta = 25°C)

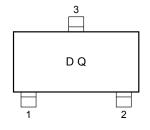
Characteristics		Symbol	Rating	Unit	
Drain-Source voltage		V_{DS}	-30	V	
Gate-Source voltage		V_{GSS}	<u>±</u> 20	V	
Drain current	DC	I _D	-100	mA	
	Pulse	I_{DP}	-200		
Drain power dissipation (Ta = 25°C)		P_{D}	100	mW	
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	

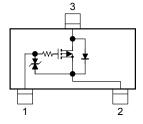


Weight: 0.0024 g(typ.)

Marking

Equivalent Circuit (top view)





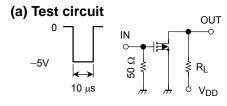
Handling Precaution

When handling individual devices (which are not yet mounting on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

www.DataSheElectrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	MIN.	TYP.	MAX.	UNIT	
Gate leakage current		I _{GSS}	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$	_	_	±1	μА	
Drain-Source breakdown voltage		V (BR) DSS	$I_D = -0.1 \text{ mA}, V_{GS} = 0$	-30	_	_	V	
Drain cut-off current		I _{DSS}	$V_{DS} = -30 \text{ V}, V_{GS} = 0$	_	_	-1	μА	
Gate threshold voltage	:	V_{th}	$V_{DS} = -3 \text{ V}, I_{D} = -0.1 \text{ mA}$	-1.1	_	-1.7	V	
Forward transfer admittance		Y _{fs}	$V_{DS} = -3 \text{ V}, I_D = -10 \text{ mA}$	20	_	_	mS	
Drain-Source ON resistance		R _{DS (ON)}	$I_D = -10 \text{ mA}, V_{GS} = -4 \text{ V}$	_	8	12	Ω	
			$I_D = -1 \text{ mA}, V_{GS} = -2.5 \text{ V}$	_	14	32	22	
Input capacitance		C _{iss}		_	9.1	_	pF	
Reverse transfer capacitance		C _{rss}	$V_{DS} = -3 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	3.5	_	pF	
Output capacitance		Coss		_	8.6	_	pF	
Switching time	Turn-on time	t _{on}	$V_{DD} = -5 \text{ V}, I_{D} = -10 \text{ mA},$	_	65		ns	
	Turn-off time	t _{off}	V _{GS} = 0~-5 V	_	175			

Switching Time Test Circuit



 $V_{DD} = -5 V$ Duty ≦ 1%

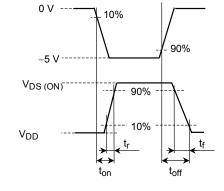
 V_{IN} : t_r , $t_f < 5$ ns

Common Source

 $(Z_{out} = 50 \Omega)$ $Ta = 25^{\circ}C$



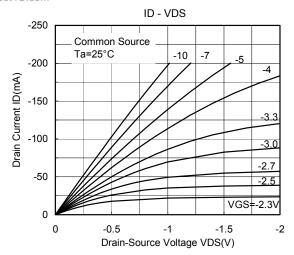


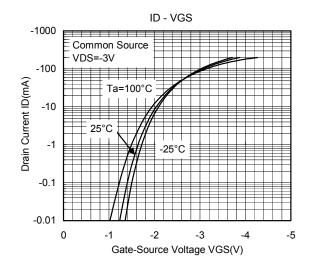


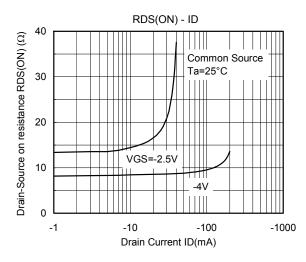
Precaution

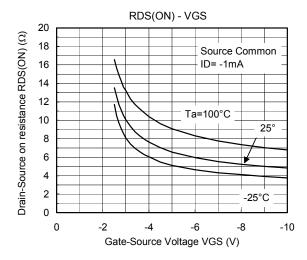
 V_{th} can be expressed as voltage between gate and source when low operating current value is $I_D = -100~\mu A$ for this product. For normal switching operation, VGS (on) requires higher voltage than Vth and VGS (off) requires lower voltage than V_{th} . (Relationship can be established as follows: $V_{GS (off)} < V_{th} < V_{GS (on)}$)

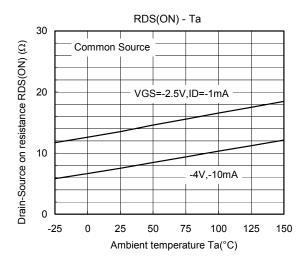
Please take this into consideration for using the device. VGS recommended voltage of -2.5 V or higher to turn on this product.

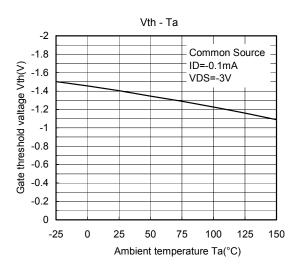


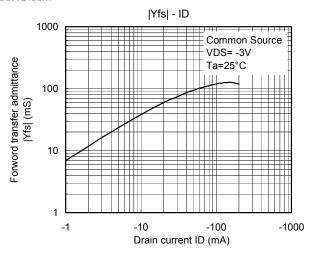


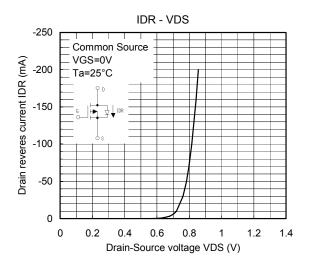


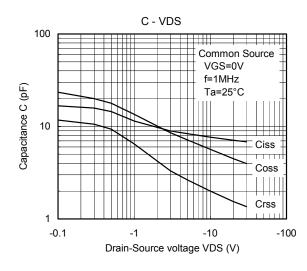


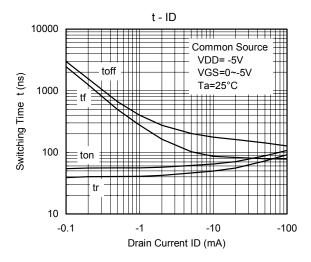


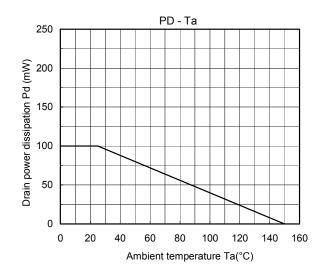












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Handbook" etc..

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